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Recent Advances in Wide Bandgap Semiconductors

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Message from the Guest Editors

Dear Colleagues,

In this Special Issue, we encourage scholars involved in WBG semiconductors to discuss key topics in the field and submit original articles as well as review articles to this Special Issue.

The subject areas include but are not limited to the following:

- Material growth, including GaN, AlN, SiC, Ga2O3, Diamond, etc.;
- Transistors based on WBG semiconductors;
- UV detectors based on WBG semiconductors;
- LED/LD based on WBG semiconductors;
- Novel devices based on WBG semiconductors;
- New processing/technique/design for WBG semiconductors;
- Power electronics circuits based on WBG semiconductors;
- Power amplifiers based on WBG semiconductors;
- MMIC;
- Other electronic or optoelectronic devices based on WBG semiconductors;
- Reliability;
- Novel applications for WBG semiconductors;
- Interdisciplinary research for WBG semiconductors, such as transparent electronics and flexible electronics.











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Message from the Editor-in-Chief

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